

SMD-codes

DATABOOK

SMD-codes.

BGA and DFN cases active SMD semiconductor components marking codes.

- 131.500 semiconductor components SMD-codes:
- Diodes, Transistors, Integrated circuits
- Case pin assignment
- Pinout
- Marking style
- Schematic diagram
- Additional SMD info
- Case drawings
- Manufacturers



2024-2025 EDITION



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ELECTRONICS COMPONENTS

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BGA and DFN cases
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Chisinau, Toronto, 2024-2025
<http://www.turuta.md>



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Introduction

At earlier eighties began a trend to replace a traditional through-hole technique with the surface mounted technology (SMT) using surface mounted devices (SMD). The SMT, although intended in principle for automatic manufacturing only expand more and more, even into a hobby world. This trend will continue, because many new components are available in SMD versions only. The SMT technique opens advantages and new applications through miniaturising of the components and increasing of reliability. The industry standard unfortunately allows that most of the SMD components does not have a clear description. Since a tiny size of the components, they are labelled with one, two or more character or graphic SMD code. Thus it is necessary to take into account that the colour and (or) placing of alphanumeric or graphic symbols are also important. Therefore a sure identification of the components is impossible without appropriate technical documentation. Moreover the polarity and pin - outs of different components could be not identified without data sheets.

Identifying the manufacturers type number of an SMD device from the package code can be a difficult task. Unfortunately, each device code is not necessarily unique.

For various manufacturers it is possible to place different devices in the same case with the same SMD-code. For example, with a **6H** SMD-code in a SOT-23 case might be either a npn-transistor **BC818** (CDIL) or a capacitance-diode **FMMV2104** (Zetex) or a n-channel JFET transistor **MMBF5486** (Motorola) or a pnp-digital transistor **MUN2131** (Motorola) or a pnp-digital transistor **UN2117** (Panasonic) or a CMOS-integrated circuit- voltage detector with reset output **R3131N36EA** (Ricoch). Even the same manufacturer may use the same code for different devices.

To identify a particular SMD device, is necessary to identify the manufacturer, package type and note the SMD code printed on the device.

The identification of the manufacturer is possible only if on the case are printed the manufacturer's logos, but it not always happens. Besides, sometimes, it is possible to determine the manufacturer with indirect tags. Many recent ON Semiconductor devices have a small superscript letter after the device code, such as **SA^c** (this smaller letter is merely a month of manufacture code). Infineon devices usually have a lower case '**s**' (**ATs, LOs**). NXP (Philips) devices usually have a lower case '**p**' (**AHp, Z1p, pB0**) or '**'** (**DQ-, -ZS**) for the devices made in Hong Kong, '**t**' (**tT9, Y7t**) for the devices made in Malaysia, "**W**" (**WT9, Y7W**) for the devices made in China. In section 19 are submitted the logos of the SMD devices manufacturers.

The package type is another problem for the identification of SMD devices. The different manufacturers can designate identical cases concerning by the various standards (or concerning by the internal system). Besides, the various cases can have an identical kind (form) and differ only by sizes. This distinction of sizes so it is not enough, that can be is measured only by special measuring devices.

Compliance with the name and type of cases from different manufacturers is solved by applying in the column "Case" an equivalent type name for equivalent cases.

In addition to SMD-code, upper case may be put padding alpha-numeric information (usually by another font or size of characters, also may be by other arrangement). Relationship position of the SMD-code and padding information have defined as style and show in the column "Style"

In the following tables sections the SMD semiconductor components - irrelevant as to whether it is dealing with transistors, diodes, integrated circuits etc. are placed in separate tables according to numbers of terminals and (or) type of cases and are listed in alpha-numeric order by SMD-codes.

Column 1 ("SMD-Code")

Column 2 ("Type")

The type designations correspond to those of the respective manufacturer documentations.

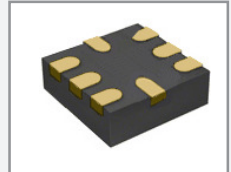
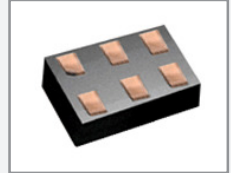
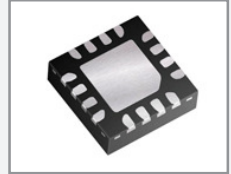
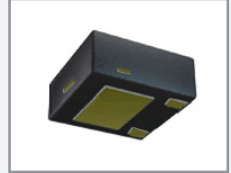
Column 3 ("Function")

Short definition of the semiconductor component.

Used abbreviations:

BM-IC	Battery Management integrated circuit	LDR-IC	LED driver integrated circuit
BR	Bridge Rectifier	Lin-IC	Linear integrated circuit
C-diode	Capacitance diode (varactor, varicap)	LVR-IC	Linear voltage regulator integrated circuit
CMOS-Log	CMOS logic integrated circuit	LVR/Vdet-IC	Linear voltage regulator/Voltage detector combined integrated circuit
Comp-IC	Voltage comparator integrated circuit	MMIC	Monolithic Microwave Integrated Circuit
DC/DC-IC	DC/DC voltage converter integrated circuit	-MOSFET	Metal-Oxide-Semiconductor FET
ESDP-diode	ElectroStatic Discharge Protection diode	-MESFET	MEtal-Semiconductor FET
ESD-Prot	ElectroStatic Discharge Protection thyristor	n-	n-channel junction transistor
-FET	Field Effect Transistor	n/p-	n-channel and p-channel transistors area
HEMT	High electron mobility transistors	Op-IC	Operational amplifier integrated circuit
H-IC	Hall-effect sensor integrated circuit	p-	p-channel junction transistor
HSPS-IC	High-side power switch integrated circuit	PDS-IC	Power distribution switch integrated circuit
IGBT	Insulated Gate Bipolar Transistor	PHEMT	Pseudomorphic high electron mobility transistors
IGBT+Di	Insulated Gate Bipolar Transistor with antiparallel diode	PIN-diode	Diode with a wide, undoped intrinsic semiconductor region
		PSW-IC	Power Switch IC
		Si-diode	Silicon diode
		SiGe-diode	Silicon/Germanium diode
		Si-npn	Silicon npn transistor
		Si-n/p	Silicon npn and pnp transistors area
		Si-npn-Darl	Silicon npn Darlington transistor

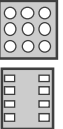
SECTION 1
BGA and DFN case SMD semiconductor components



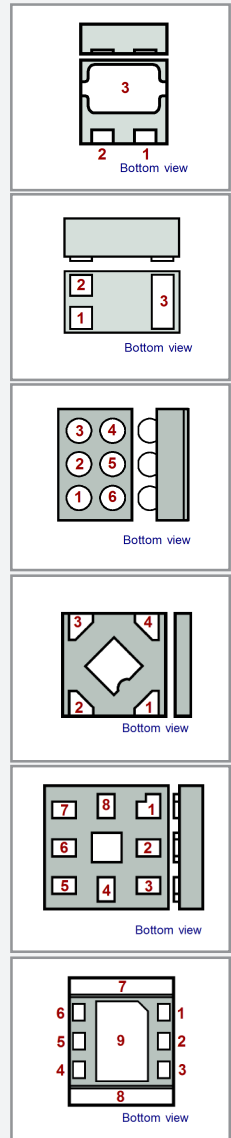
SMD code	Type	Function	Case	Style	Short description	Atr	A.d. Pin	Sch	Mnf
+AAT	MAX9724AETC+	Lin-IC	QFN-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 38	-	Max
+AAU	MAX9724BETC+	Lin-IC	QFN-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 38	-	Max
+AAW	MAX9718BETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+AAX	MAX9718CETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+AAY	MAX9718DETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+ABJ	MAX9724CETC+	Lin-IC	QFN-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 38	-	Max
+ABK	MAX9724DETC+	Lin-IC	QFN-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 38	-	Max
+ADH	MAX9724AEBEC+T	Lin-IC	BGA-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 39	-	Max
+ADI	MAX9724BEBC+T	Lin-IC	BGA-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 39	-	Max
+ADX	MAX9718BEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+ADZ	MAX9718CEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AEA	MAX9718DEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AEH	MAX9724DEBC+T	Lin-IC	BGA-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 39	-	Max
+AEV	MAX98306ETD+	Lin-IC	DFN-14	9ac	APA, BTL, 2.7..5.5V, 2x3.7W (5V/4Ω), shutdown	-	- 37	-	Max
+AFB	MAX9718EEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AFC	MAX9718FEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AFD	MAX9718GEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AFE	MAX9718HEBL+TG45	Lin-IC	BGA-9	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 39	AFP54	Max
+AGE	MAX9724CEBC+T	Lin-IC	BGA-12	9m	APA, 2.7..5.5V, 2x60mW (3V/32Ω), shutdown	-	- 39	-	Max
+AIN	MAX98307ETE+	Lin-IC	QFN-16	9ac	APA, BTL, class-D, 2.7..6.6V, 3.3W (5V/3Ω), shutdown	-	- 38	-	Max
+AIY	MAX98309EWL+	Lin-IC	BGA-9	9ac	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), shutdown	-	- 39	-	Max
+AIZ	MAX98310EWL+	Lin-IC	BGA-9	9ac	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), shutdown	-	- 39	-	Max
+ASY	MAX9718EETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+ASZ	MAX9718FETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+ATA	MAX9718GETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
+ATB	MAX9718HETB+T	Lin-IC	DFN-10	9m	APA, BTL, 2.7..5.5V, 1.4W (5V/4Ω), select shutdown	-	- 37	AFP20	Max
0	FP6121-AWDG	LVR-IC	TDFN-6	9m	LDO, Dual out, Vout1/Vout2=3.3V/2.8V±2%, 150mA, +CEV, Green pack.	-	- 56xv	VR19	Fit
0	TCR3UG30A	LVR-IC	WCSP4F	9m	LDO, 3.0V±1%, 300mA, +CE, CL	H16a	- 63bc*	VR4	Tos
0	TCR3UG30B	LVR-IC	WCSP4F	9m	LDO, 3.0V±1%, 300mA, +CE	H16b	- 63bc*	VR4	Tos
0	TCR4DG30	LVR-IC	WCSP4E	9m	LDO, 3.0V±1%, 420mA, +CE	H16a	- 63bc*	VR4	Tos
00	RP110L081B	LVR-IC	DFN1010-4	9ac	LDO, 0.8V±1%, 150mA, +CE	-	- 48vm	VR4	Ric
00	XC6129C55A9R-G	Vdet-IC	USPQ-4B05	9ad	5.5V±0.8%, -Reset PPO, Rel. Delay	H33b	05 115r2	VD3a	Tor
00	XC6129N55A9R-G	Vdet-IC	USPQ-4B05	9ad	5.5V±0.8%, -Reset ODO, Rel. Delay	H33a	05 115r2	VD1a	Tor
00	XC6224A0817R	LVR-IC	USPN-4B02	9e	LDO, 0.8V±20mV, 150mA, +CE	-	05 58vm	VR4	Tor
00	XC6229D1211R-G	LVR-IC	BGA-4	9ac	LDO, 1.2V±20mV, 300mA, +CE	-	09 63ba*	VR4	Tor
0001 1000	PDTA124XMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, R1/R2=22k/47k	-	- 172ta	-	Nxp
0001 1001	PDTA114EMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=10k/10k	-	- 172ta	-	Nxp
0001 1100	PDTA113EMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=1k/1k	-	- 172ta	-	Nxp
0001 1101	PDTA113ZMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=1k/10k	-	- 172ta	-	Nxp
0001 1110	PDTA114TMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1=10k	-	- 172ta	-	Nxp
0001 1111	PDTA114YMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=10k/47k	-	- 172ta	-	Nxp
0010 0000	PDTA115EMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=100k/100k	-	- 172ta	-	Nxp
0010 0001	PDTA115TMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1=100k	-	- 172ta	-	Nxp
0010 0010	PDTA123EMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=2.2k/2.2k	-	- 172ta	-	Nxp
0010 0011	PDTA123TMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1=2.2k	-	- 172ta	-	Nxp
0010 0100	PDTA123YMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=2.2k/10k	-	- 172ta	-	Nxp
0010 0101	PDTA124EMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, R1/R2=22k/22k	-	- 172ta	-	Nxp
01	RP110L091B	LVR-IC	DFN1010-4	9ac	LDO, 0.9V±1%, 150mA, +CE	-	- 48vm	VR4	Ric
01	TS4601EIJT	Lin-IC	BGA-16	9p	APA, 2.7..5.5V, 2x75mW (5V/16Ω), stand-by, I2C	-	- 39	-	Ste
01	XC6224A0917R	LVR-IC	USPN-4B02	9e	LDO, 0.9V±20mV, 150mA, +CE	-	05 58vm	VR4	Tor
01	XC6229D12B1R-G	LVR-IC	BGA-4	9ac	LDO, 1.25V±20mV, 300mA, +CE	-	09 63ba*	VR4	Tor
01	XC6420AB017R-G	LVR-IC	USPN-6	9ac	LDO, Dual out, Vout1/Vout2=1.20/1.20V±2%, 150mA, +CE	-	05 52xv	VR19	Tor
01	XC6420AB01DR-G	LVR-IC	USP-6B04	9ac	LDO, Dual out, Vout1/Vout2=1.20/1.20V±2%, 150mA, +CE	-	05 73x4	VR19	Tor
0100 1001	PDTA123JMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, 180MHz, R1/R2=2.2k/47k	-	- 172ta	-	Nxp
011	AP64011-GU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.3V±2%, 250mA, +CE, H-free	H22g	- 56xv	VR19	Anw
011	AP64011-PU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.3V±2%, 250mA, +CE	-	- 56xv	VR19	Anw
011	EC49222-1-FFF	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.3V±2%, 250mA, +CE, L-free	H22f	14 56xv	VR19	Ecm
011	EC49222-1-FFG	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.3V±2%, 250mA, +CE, H-free	H31	14 56xv	VR19	Ecm
0111 1011	PDTA124TMB	Si-pnp-Digi	DFN1006B-3	9za	Sw, 50V, 100mA, 250mW, R1=22k	-	- 172ta	-	Nxp
012	AP64012-GU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.8V/3.0V±2%, 250mA, +CE, H-free	H22g	- 56xv	VR19	Anw
012	AP64012-PU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.8V/3.0V±2%, 250mA, +CE	-	- 56xv	VR19	Anw
012	EC49222-2-FFF	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.8V/3.0V±2%, 250mA, +CE, L-free	H22f	14 56xv	VR19	Ecm
012	EC49222-2-FFG	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.8V/3.0V±2%, 250mA, +CE, H-free	H31	14 56xv	VR19	Ecm
013	AP64013-GU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.0V±2%, 250mA, +CE, H-free	H22g	- 56xv	VR19	Anw
013	AP64013-PU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.0V±2%, 250mA, +CE	-	- 56xv	VR19	Anw
013	EC49222-3-FFF	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.0V±2%, 250mA, +CE, L-free	H22f	14 56xv	VR19	Ecm
013	EC49222-3-FFG	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.0V/3.0V±2%, 250mA, +CE, H-free	H31	14 56xv	VR19	Ecm
014	EC49222-4-FFF	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.3V/2.8V±2%, 250mA, +CE, L-free	H22f	14 56xv	VR19	Ecm
014	EC49222-4-FFG	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=1.3V/2.8V±2%, 250mA, +CE, H-free	H31	14 56xv	VR19	Ecm
01A	AP6401A-GU	LVR-IC	UFN-6	9ia	LDO, Dual out, Vout1/Vout2=3.3V/3.3V±2%, 250mA, +CE, H-free	H22g	- 56xv	VR19	Anw

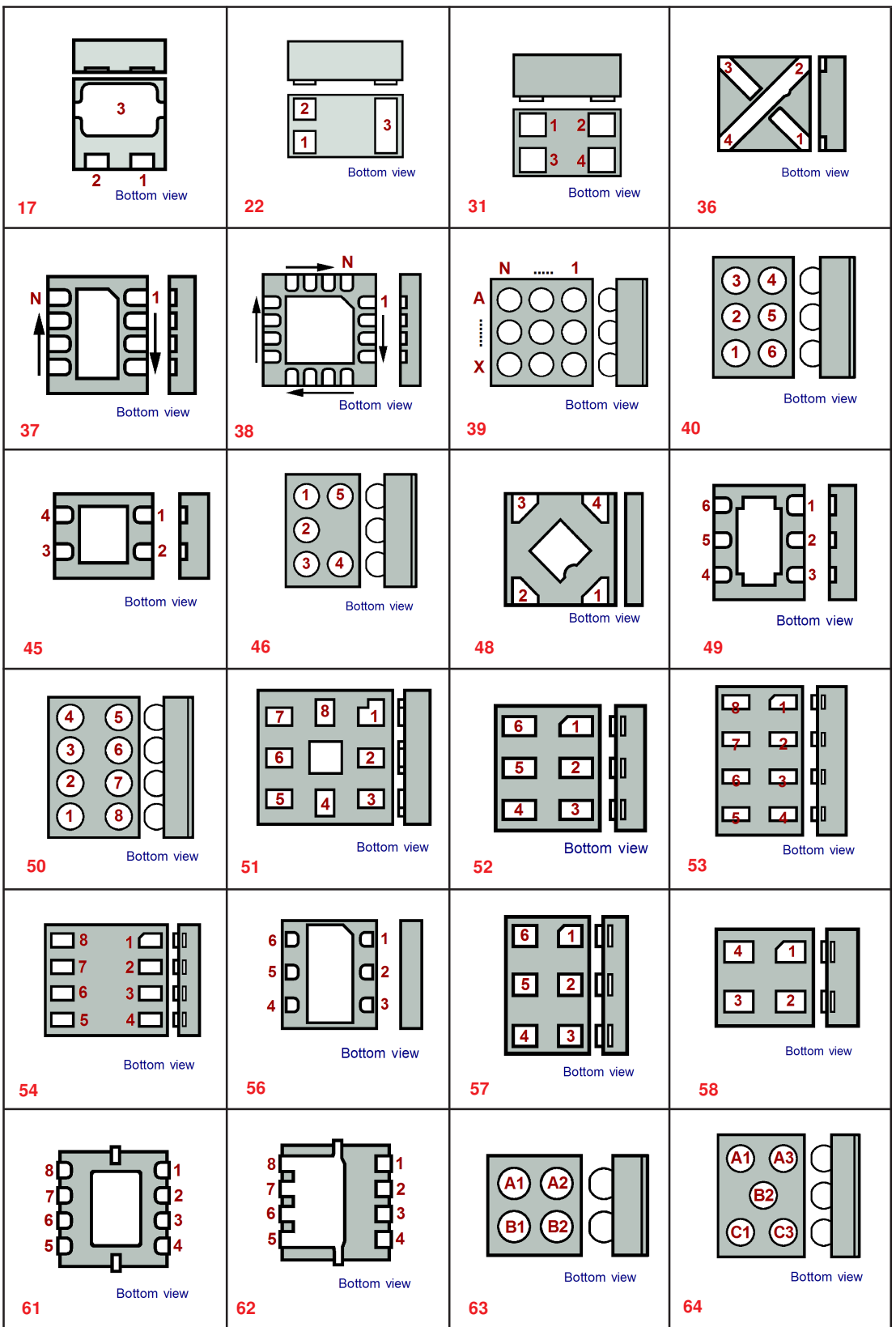


SMD code	Type	Function	Case	Style	Short description	Atr	A.d.	Pin	Sch	Mnf
ZPC	XC9142F50D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.0V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPC	XC9142F50DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.0V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZPD	XC9142F51D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.1V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPD	XC9142F51DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.1V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZPE	XC9142F52D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.2V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPE	XC9142F52DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.2V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZPF	XC9142F53D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.3V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPF	XC9142F53DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.3V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZPH	XC9142F54D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.4V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPH	XC9142F54DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.4V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZPK	XC9142F55D0R-G	DC/DC-IC	WLP-6-01	9ac	PWM st-up, 3.0MHz, 5.5V±2%, +CE (compl. out discon.)	H01	05	40he	DC19a	Tor
ZPK	XC9142F55DER-G	DC/DC-IC	USP-6C	9ac	PWM st-up, 3.0MHz, 5.5V±2%, +CE (compl. out discon.)	H01	05	49he	DC19a	Tor
ZR	74AVCH1T45FW3	CMOS-Log	X2-DFN0910-6	9ij	Dual supply translating transceiver with 3-state output	-	61	52	Log95	Di
ZR	XC6501D4817R-G	LVR-IC	WLP-4-01	9ad	LDO, 4.8V±1%, 200mA, +CE, CL, PDR	-	05	63bk*	VR4	Tor
ZS	XC6501D48A7R-G	LVR-IC	WLP-4-01	9ad	LDO, 4.85V±1%, 200mA, +CE, CL, PDR	-	05	63bk*	VR4	Tor
ZT	XC6501D4917R-G	LVR-IC	WLP-4-01	9ad	LDO, 4.9V±1%, 200mA, +CE, CL, PDR	-	05	63bk*	VR4	Tor
ZU	XC6501D49A7R-G	LVR-IC	WLP-4-01	9ad	LDO, 4.95V±1%, 200mA, +CE, CL, PDR	-	05	63bk*	VR4	Tor
ZV	XC6501D5017R-G	LVR-IC	WLP-4-01	9ad	LDO, 5.0V±1%, 200mA, +CE, CL, PDR	-	05	63bk*	VR4	Tor
ZVE	TS12A12511DRJ	CMOS-Log	QFN-8	9me	Single-pole/double-throw analog switch	-	-	75	Log130	Ti
ZX	XC6221B48B7R	LVR-IC	USPN-4	9ac	LDO, 4.85V±1%, 200mA, +CE, CL	-	05	58vm	VR4	Tor
ZY	XC6221B49B7R	LVR-IC	USPN-4	9ac	LDO, 4.95V±1%, 200mA, +CE, CL	-	05	58vm	VR4	Tor
ZZ	NC7S86L	CMOS-Log	MicroPak-6	9ub	2-input EXCLUSIVE-OR gate	-	-	57	Log5a	F
ZZ306	XC9225G306D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.0V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ30C	XC9225G30CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.0V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ316	XC9225G316D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.1V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ31C	XC9225G31CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.1V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ326	XC9225G326D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.2V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ32C	XC9225G32CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.2V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ336	XC9225G336D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.3V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ33C	XC9225G33CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.3V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ346	XC9225G346D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.4V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ34C	XC9225G34CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.4V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ356	XC9225G356D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.5V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ35C	XC9225G35CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.5V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ366	XC9225G366D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.6V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ36C	XC9225G36CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.6V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ376	XC9225G376D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.7V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ37C	XC9225G37CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.7V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ386	XC9225G386D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.8V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ38C	XC9225G38CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.8V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ396	XC9225G396D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.9V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ39C	XC9225G39CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.9V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3A6	XC9225G3A6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.05V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3AC	XC9225G3ACD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.05V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3B6	XC9225G3B6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.15V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3BC	XC9225G3BCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.15V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3C6	XC9225G3C6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.25V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3CC	XC9225G3CCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.25V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3D6	XC9225G3D6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.35V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3DC	XC9225G3DCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.35V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3E6	XC9225G3E6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.45V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3EC	XC9225G3ECD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.45V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3F6	XC9225G3F6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.55V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3FC	XC9225G3FCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.55V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3H6	XC9225G3H6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.65V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3HC	XC9225G3HCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.65V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3K6	XC9225G3K6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.75V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3KC	XC9225G3KCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.75V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3L6	XC9225G3L6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.85V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3LC	XC9225G3LCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.85V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3M6	XC9225G3M6D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 3.95V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ3MC	XC9225G3MCD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 3.95V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ406	XC9225G406D	DC/DC-IC	USP-6B	9b	PWM st-dwn, 600kHz, 4.0V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor
ZZ40C	XC9225G40CD	DC/DC-IC	USP-6B	9b	PWM st-dwn, 1.2MHz, 4.0V±1%, 900mA, +CE, PDR	-	09	49dc5	DC1	Tor



SECTION 2
Conventional case drawings. Pin assignment





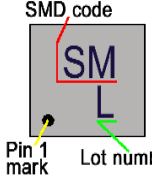
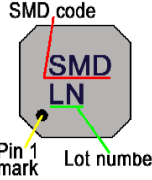
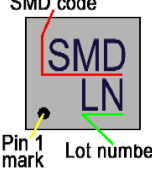


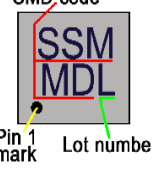

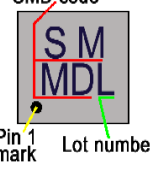
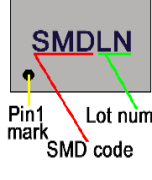

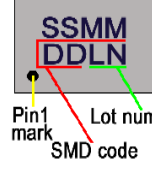
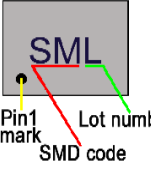
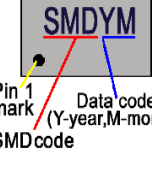
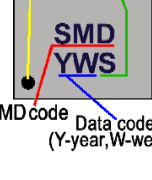
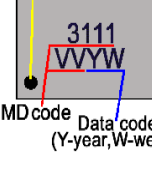
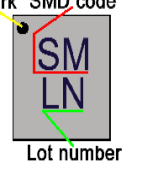
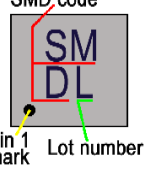
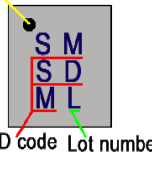
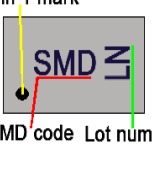
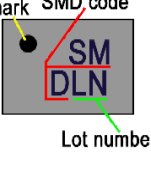

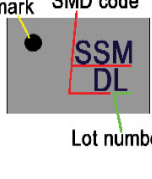
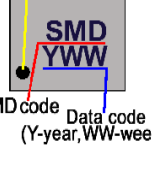
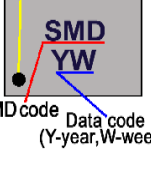
SECTION 3
Pinout (table)



	PIN 1	PIN2	PIN3	PIN4	PIN5	PIN6	PIN7	PIN8
a0	GND	Output	Vcc	+Input	-Input	-	-	-
a1	GND	GND	Input	GND	GND	Vcc/Output	-	-
a2	N/C	Anode	Cathode	N/C	Adjust	-	-	-
a3	CE	GND	Vinput	Voutput	Adjust	N/C	-	-
a4	CE	Vinput	Voutput	Switch	GND	Feedback	-	-
a5	No data.	See datash.	See sch	-	-	-	-	-
a7	CE	GND	SSC	Vinput	Voutput	-	-	-
a8	Test	GND	Tdet	N/C	Vcc	-	-	-
a9	Tdet	GND	Test	Vcc	-	-	-	-
aa	Input	GND	Vcc/Output	GND	-	-	-	-
aa*	A1=CE/MODE	A3=Voutput	B2=Lx	C1=Vinput	C3=GND	-	-	-
ab	Input	GND	GND	Output	GND	Vcc	-	-
ab*	A1=CE/MODE	A3=Feedb.	B2=Lx	C1=Vinput	C3=GND	-	-	-
ac	Vcc	GND	Input	GND	GND	Output	GND	GND
ac*	A1-CE	A2=Vinput	B1=GND	B2=Voutput	-	-	-	-
ad	Input	GND	Vcc	Output	GND	-	-	-
ae	Input	Vcc	GND	Output	GND	GND	-	-
af	N/C	Vinput	N/C	GND	N/C	Voutput	N/C	N/C
ag	Contact	Contact	N/C	-	-	-	-	-
ah	Emitter	Emitter	Base	Emitter	Emitter	Collector	-	-
ai	GND	Vcc	Input	Output	-	-	-	-
aj	GND	Vcc/Vout	GND	Input	-	-	-	-
ak	N/C	Cathode	Anode	-	-	-	-	-
am	Vcc/Output	GND	Input	GND	-	-	-	-
an	Output	GND	Input	Vcc	GND	-	-	-
ao	Cath.(Anode)	N/C	Cath.(Anode)	An.(Cath.)	-	-	-	-
ap	Cathode	N/C	Cathode	Anode	-	-	-	-
aq	Contact	N/C	Contact	-	-	-	-	-
ar	Contact	Contact	-	-	-	-	-	-
as	Emitter	Emitter	N/C	Base	Collector	Collector	Collector	Collector
at	Cathode	Gate	Anode	-	-	-	-	-
au	CE	SS	Voutput	Vinput	GND	Vbias	-	-
av	Vbias	GND	Vinput	Voutput	SS	CE	-	-
aw	CE	lilm	Voutput	Vinput	GND	Vbias	-	-
ax	Vbias	GND	Vinput	Voutput	lilm	CE	-	-
ax*	A1=CE1	A2=Voutput1	B1=GND	B2=Vinput	C1=CE2	C2=Voutput2	-	-
ay*	A1=Voutput2	A2=Vcc	A3=Voutput1	B1=CE2	B2=GND	B3=CE1	-	-
az	Vinput	N/C	Voutput	N/C	N/C	N/C	GND	CE
b0	IN1	POS	Vin	Vout	CE	GND	IN2	NEG
b1	Terminal	Gate	Terminal	-	-	-	-	-
ba	Anode/Cath.	Anode/Cath.	-	-	-	-	-	-
ba*	A1=GND	A2=Voutput	B1=CE	B2=Vinput	-	-	-	-
bb	Cathode1	Cathode2	Cathode3	Anode3	Anode2	Anode1	-	-
bb*	A1=GND	A2=CE	B1=Voutput	B2=Vinput	-	-	-	-
bc*	A1=Vinput	A2=Voutput	B1=CE	B2=GND	-	-	-	-
bd	Cathode	Cathode	Anode	-	-	-	-	-
bd*	A1=GND	A2=Vcc	B1=Reset	B2=MR	-	-	-	-
be*	A1=CE	A3=Cb	B2=GND	C1=Voutput	C3=Vinput	-	-	-
bf*	A1=Output L	A2=GND	A3=Output R	B1=Input L	B3=Input R	C1=Shutdown	C2=Vcc	C3=Cext
bg	Cathode1	Cathode2	Anode2	N/C	Anode1	-	-	-
bg*	A1=Voutput	A2=Vinput	B1=Adj	B2=CE	C1=GND	C2=Vbias	-	-
bh	Anode1	Com. Cath.	Anode2	Anode3	Anode4	-	-	-
bh*	A1=GND	A3=CE	B2=Cb	C1=Voutput	C3=Vinput	-	-	-
bi	Anode	Cathode	Anode	Anode	Cathode	Anode	-	-
bj*	A1=Voutput	A2=Vinput	B2=GND	C1=CE	C2= Vbias	-	-	-
bk*	A1=Voutput	A2=Vinput	B1=GND	B2=CE	-	-	-	-
bm1	N/C	Cout	Dout	GND	V+	V-	-	-
bm2	V-	V+	GND	Dout	Cout	-	-	-
bn	OVP	Vinput	CE	A GND	N/C	Feedback	Switching	P GND
bp	Cathode	Cathode	Anode	Anode	Cathode	Cathode	-	-
bq	GND	Voutput	Lx	-	-	-	-	-
br	GND	Voutput	Ext	-	-	-	-	-


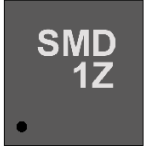




















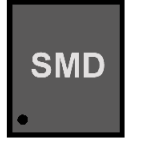

SECTION 4
BGA and DFN cases SMD-code marking style



<p>9aa</p>  <p>SMD code SM Lot number L Pin 1 mark</p>	<p>9ab</p>  <p>SMD code SMD Lot number LN Pin 1 mark</p>	<p>9ac</p>  <p>SMD code SMD Lot number LN Pin 1 mark</p>	<p>9ad</p>  <p>SMD code SM Lot number LN Pin 1 mark</p>
<p>9ae</p>  <p>SMD code SM Lot number LN Pin 1 mark</p>	<p>9b</p>  <p>SMD code SSM Lot number MDL Pin 1 mark</p>	<p>9ba</p>  <p>SMD code SSM Lot number DLN Pin 1 mark</p>	<p>9bb</p>  <p>SMD code SM Lot number MDL Pin 1 mark</p>
<p>9c</p>  <p>SMD code SMDLN Pin 1 mark Lot number</p>	<p>9ca</p>  <p>Manufacturer name TOREX SMD code SMDLN Pin 1 mark Lot number</p>	<p>9cb</p>  <p>SMD code SSMM Lot number DDLN Pin 1 mark</p>	<p>9cd</p>  <p>SMD code SML Pin 1 mark Lot number</p>
<p>9d</p>  <p>SMD code SMDYM Pin 1 mark Data code (Y-year, M-month) SMD code</p>	<p>9da</p>  <p>SMD code SMD Lot number YWS Pin 1 mark Sequence Data code (Y-year, W-week)</p>	<p>9db</p>  <p>SMD code 3111 Lot number VVYW Pin 1 mark Data code (Y-year, W-week)</p>	<p>9e</p>  <p>SMD code SM Lot number LN Pin 1 mark SMD code</p>
<p>9ea</p>  <p>SMD code SM Lot number DL Pin 1 mark</p>	<p>9f</p>  <p>SMD code SM Lot number SD M L Pin 1 mark</p>	<p>9g</p>  <p>SMD code SMD Lot number Pin 1 mark</p>	<p>9h</p>  <p>SMD code SM Lot number DLN Pin 1 mark SMD code</p>
<p>9ha</p>  <p>SMD code SM Lot number DL Pin 1 mark SMD code</p>	<p>9hb</p>  <p>SMD code SSM Lot number DL Pin 1 mark SMD code</p>	<p>9i</p>  <p>SMD code SMD Lot number YWW Pin 1 mark Data code (Y-year, WW-week)</p>	<p>9ia</p>  <p>SMD code SMD Lot number YW Pin 1 mark Data code (Y-year, W-week)</p>

SECTION 5
BGA and DFN cases SMD-code attribute



<p>H01</p> 	<p>H02</p> 	<p>H03</p> 	<p>H04</p> 
<p>H05</p> 	<p>H06</p> 	<p>H07</p> 	<p>H08</p> 
<p>H09</p> 	<p>H10</p> 	<p>H11</p> 	<p>H12</p> 
<p>H13</p> 	<p>H14</p> 	<p>H15</p> 	<p>H16</p> 
<p>H16a</p> 	<p>H16b</p> 	<p>H17</p> 	<p>H18</p> 
<p>H19</p> 	<p>H20</p> 	<p>H21</p> 	<p>H22</p> 

SECTION 6
Additional production data info



Besides SMD code, the manufacturers can place additional information such as **internal production lot number**, **traceability code**, **data of production**, **assembly location** etc. The additional info is an arbitrary position and arbitrary content (depending of the manufacturer) and can be alphanumeric symbol (symbols) or graphic symbol.

Below we present some additional info.

Lot number.

Manufacturer: **Elm (ELM Technology Corporation):**

Rules 1 (for ODO voltage detectors)

Symbol 1 - A to Z(l, O, X excepted)

Symbol 2 - 0 to 9

Rules 2 (for PPO voltage detectors)

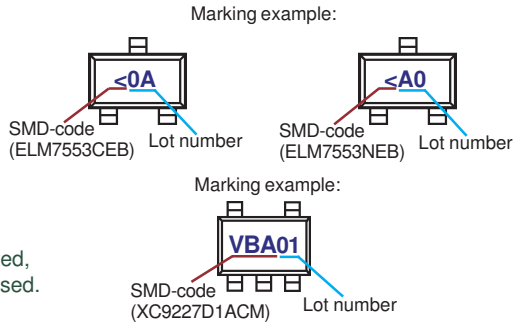
Symbol 1 - 0 to 9

Symbol 2 - A to Z(l, O, X excepted)

Manufacturer: **Tor (Torex Semiconductor LTD):**

01~09, 0A~0Z, 11~9Z, A1~A9, AA~AZ, B1~ZZ repeated,

(G, I, J, O, Q, W excluded.) * No character inversion used.



Production data

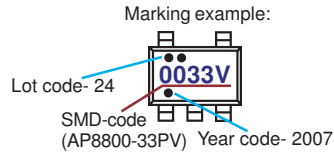
Manufacturer: **Anw (Anwell Semiconductor Corp.)**

Dot above product code: Lot Code:

1			•	17	•		•
2			•	18	•		•
3			•	19	•		•
4		•		20	•		•
5		•	•	21	•		•
6		•	•	22	•		•
7		•	•	23	•		•
8		•		24	•	•	
9		•	•	25	•		•
10		•	•	26	•		•
11		•	•	27	•		•
12		•	•	28	•		•
13		•	•	29	•		•
14		•	•	30	•		•
15		•	•	31	•		•
16		•					

Dot under product code: Year Code:

2003			
2004			
2005		•	•
2006		•	•
2007		•	
2008		•	•
2009		•	•
2010		•	•



Manufacturer: **Ape (Advanced Power Electronics Corp.)**

Code Year

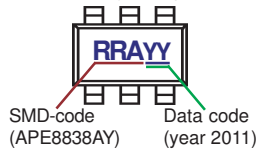
YY 2004, 2008, 2012

YY 2003, 2007, 2011

YY 2002, 2006, 2010

YY 2001, 2005, 2009

Marking example:



Manufacturer: **Axl (AXEelite Technology Co., Ltd)**

Code Year Code Week

7 2007 **A...Z** 1...26

8 2008 **a...z** 27...52

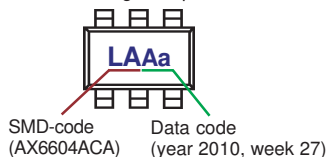
9 2009

A 2010

B 2011

C 2012

Marking example:

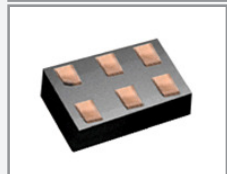


Manufacturer: **Di (Diodes Inc.)**

Y : Year : 0~9XXX

W : Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week

SECTION 7
Case drawings





ADFN1.5x1.5-6



BGA-4
BGA-4A
CB4-3



BGA-5



BGA-6



BGA-8



BGA-8A



BGA-9



BGA-10



BGA-12



BGA-14



BGA-15



BGA-16



BGA-18



BGA-20



BGA-24



BGA-25



BGA-29



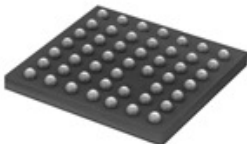
BGA-30



BGA-36



BGA-42



BGA-48



BGA-49



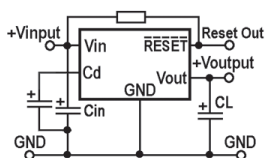
CL-2025
CL-2025-03



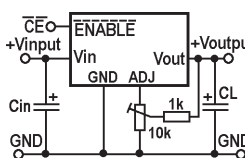
CP-6-3

SECTION 8
Sample schematic diagram

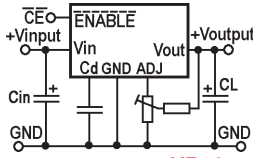




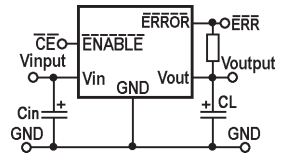
VR15b



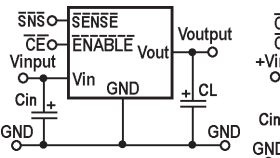
VR16



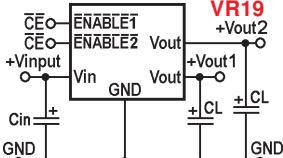
VR16a



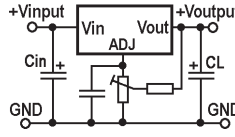
VR17



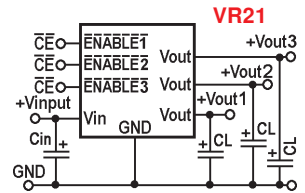
VR18



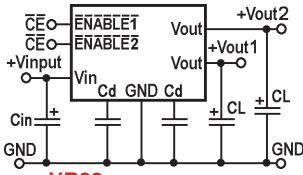
VR19



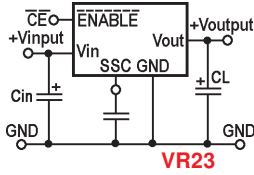
VR20



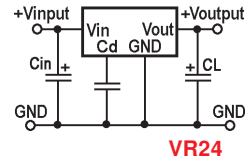
VR21



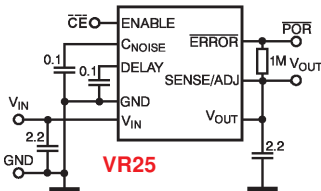
VR22



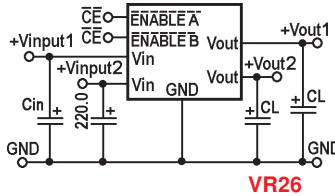
VR23



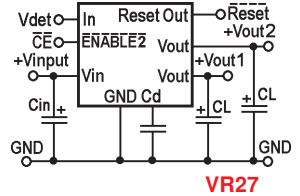
VR24



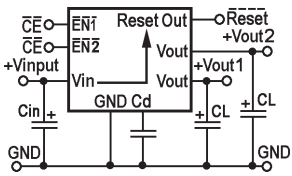
VR25



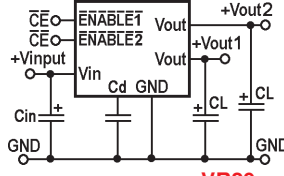
VR26



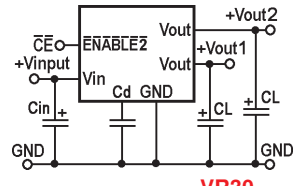
VR27



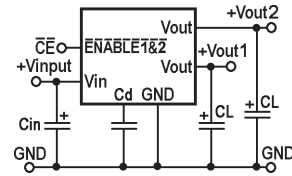
VR28



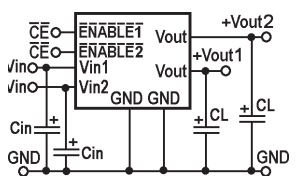
VR29



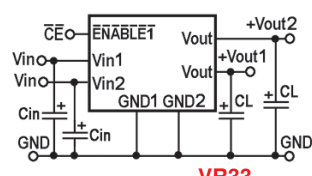
VR30



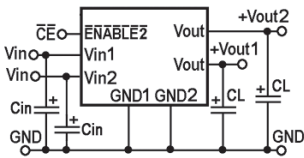
VR31



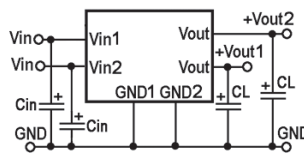
VR32



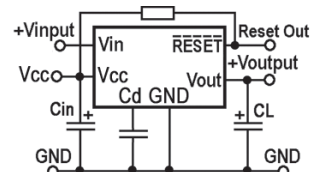
VR33



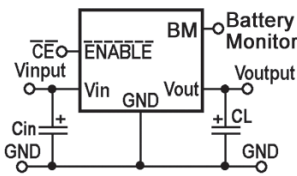
VR34



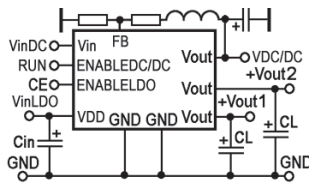
VR35



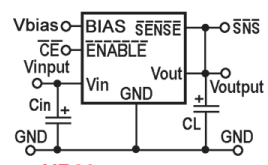
VR36



VR37



VR38



VR39



SECTION 9
Manufacturers name, logo and web page URL





Aat- Advanced Analog Technology
<http://www.aatech.com.tw/index.aspx>



Abi- ABLIC Inc.
<https://www.ablicinc.com/en/semicon/>



Ad- Analog Devices
<http://www.analog.com>



Adt- ADDtek
<http://www.addmtek.com/Index.htm>



Afs- Analog Future Chip Co., Ltd.
<http://www.afsemi.com/>



Agi- Agilent Technologies
www.semiconductor.agilent.com



Aic- Analog Integrations Corporation
<http://www.analog.com.tw>



Ali- Alliance Semiconductor
<http://www.alsc.com>



All- Allegro MicroSystems Inc.
<http://www.allegromicro.com>



Alt- Aolittel Technology Co., Ltd
<http://www.aolittel.com>



Ame- AME, Inc.
www.ame.com.tw



Ams- AMOS Technology Limited
<http://www.amos-tech.com>



Amz- Amazing Microelectronic
<http://www.amazingIC.com>



Ana- Anachip Corp.
www.anachip.com.tw



Anb- Anbon Semiconductor Co., Ltd.
<http://www.anbonsemi.com>



Anp- Anpec Electronics Corp.
www.anpec.com.tw



Ans- AnaSem Inc.
<http://www.anasem.net/>



Ant- Advanced Analogic Technologies, Inc.
<http://www.analogictech.com>



Anv- Anova Technologies Co. Ltd
<http://anova-semi.com/>



Anw- Anwell Semiconductor Corp.
<http://www.ansc.com.tw/>



Aom- Alpha & Omega Semiconductor
<http://www.aosmd.com/>



Yea- Yeashin Technology Co., Ltd
<http://www.yeashin.com/>



Yen- Yenyo Technology Co., Ltd.
<http://www.yenyo.com.tw/>



Ynt- Yint Electronics Co., Ltd.
<http://www.yint.com.cn>



Zbo- Zibo Micro Commercial Components Corp.
<http://www.zbmcc.com/en/>



Zbs- Zhide Electronics Co., Ltd
<http://www.senocn.com/>



Zhd- Zibo Seno Electronic Engineering Co., Ltd.
<http://www.cz-zhide.com/>



Zlg- Zilog, Inc.
<http://www.zilog.com/>



Zow- Zowie Technology Corporation
<http://www.zowie.com.tw/>



Zx- Zetex plc.
<http://www.zetex.com>



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